

-500V High Voltage PNP Transistor

FEATURES

- Epitaxial Planar Type
- Low Saturation Voltages
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATION

- Consumer electronics
- High voltage switching
- High voltage driver

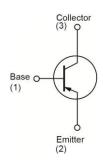
KEY PERFORMANCE PARAMETERS				
PARAMETER		VALUE	UNIT	
BV _{CBO}		-500	V	
BV _{CEO}		-500	V	
lc		-150	mA	
V _{CE(SAT)}	I _C =-50mA, I _B =-10mA	-0.5	V	











Notes: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Collector-Base Voltage	V_{CBO}	-500	V	
Collector-Emitter Voltage	V _{CEO}	-500	V	
Emitter-Base Voltage	V _{EBO} -	-5	V	
Collector Current (DC)	Ic	-150	mA	
Collector Peak Current (Pulse) Note	Ісм	-500	Α	
Power Total Dissipation @ T _A =25°C	P _D	0.3	W	
Maximum Operating Junction Temperature	TJ	+150	°C	
Storage Temperature Range	T _{STG}	-55 to +150	°C	

Note: Single pulse, Pw \leq 380 μ s, Duty \leq 2%

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	TYP	UNIT	
Junction to Ambient Thermal Resistance	Reja	162	°C/W	

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ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static (Note 1)						
Collector-Base Breakdown Voltage	I _C = -100uA, I _E = 0	ВУсво	-500			٧
Collector-Emitter Breakdown Voltage	$I_C = -10 \text{mA}, I_B = 0$	BV _{CEO}	-500			٧
Emitter-Base Breakdown Voltage	I _E = -100uA, I _C = 0	BV _{EBO}	-5			٧
Collector Cutoff Current	V _{CB} = 120V, I _E = 0	Ісво			-100	nA
Emitter Cutoff Current	$V_{EB} = 6V$, $I_C = 0$	I _{EBO}			-100	nA
Collector-Base Breakdown Voltage	I _C = -100uA, I _E = 0	ВУсво	-500			٧
Callantan Fraitten Catamatian Valtana	$I_C = -20mA$, $I_B = -2mA$	V _{CE(SAT)} 1			-0.2	V
Collector-Emitter Saturation Voltage	$I_C = -50 \text{mA}, I_B = -10 \text{mA}$	V _{CE(SAT)} 2			-0.5	
Base-Emitter Saturation Voltage	$I_C = -50 \text{mA}, I_B = -10 \text{mA}$	V _{BE(SAT)}			-0.9	٧
Base-Emitter on Voltage	V _{CE} = -10V, I _C = -50mA	V _{BE(ON)}			-0.9	٧
	$V_{CE} = -10V, I_{C} = -1mA$	h _{FE} 1	150		300	
DC Current Transfer Ratio	$V_{CE} = -10V, I_{C} = -50mA$	h _{FE} ²	80		300	
	V _{CE} = -10V, I _C = -100mA	h _{FE} ³		15		
Dynamic (Note 2)						
Transition Frequency	V _{CE} =10V, I _C =-100mA	f⊤		50		MHz
Output Capacitance	V _{CB} = 20V, f=1MHz	Cob			8	pF
Turn On Time	V _{CE} = -100V, I _C = -50mA	ton		110		ns
Turn Off Time	I _{B1} =-5mA, I _{B2} =-10mA	t _{off}		1500		ns

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Note:

- 1. Pulse test: ≤380µs, duty cycle ≤2%
- 2. For DESIGN AID ONLY, not subject to production testing

ORDERING INFORMATION

ORDERING CODE	PACKAGE	PACKING
TSA884CX RFG	SOT-23	3,000pcs / 7" Reel



ELECTRICAL CHARACTERICS CURVES (T_A=25°C, unless otherwise noted)

Figure 1. Static Characteristics

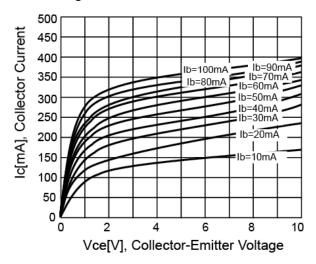


Figure 3. $V_{CE(sat)}$ vs. $V_{BE(sat)}$

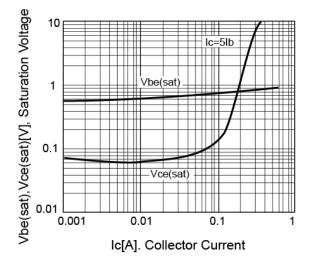


Figure 2. DC Current Gain

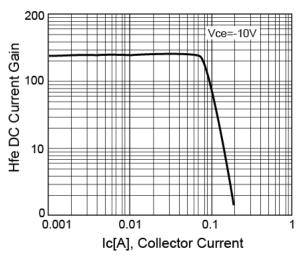
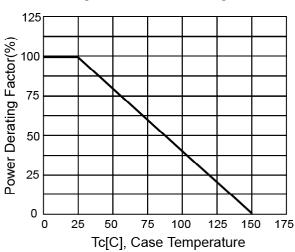


Figure 4. Power Derating



Version: F2206

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0.20

1.35 MAX

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SEATING

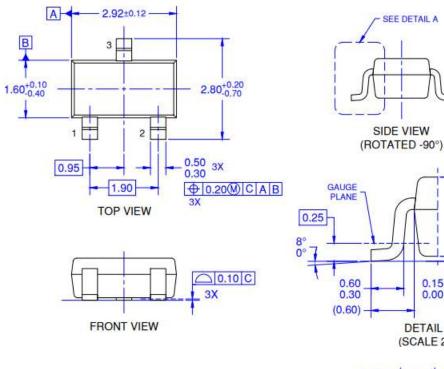
PLANE

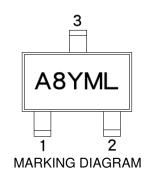
1.10+0.10



PACKAGE OUTLINE DIMENSIONS

SOT-23





A8 = Device Code

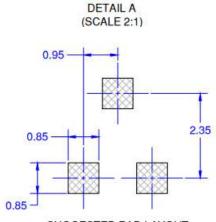
Υ = Year Code

= Month Code for Halogen Free Product М

> **P** =Feb **Q** =Mar \mathbf{R} =Apr **S** =May **T** =Jun **U** =Jul V =Aug

> W =Sep **X** =Oct Y =Nov Z =Dec

= Lot Code



0.15

0.00

SEE DETAIL A

SIDE VIEW

SUGGESTED PAD LAYOUT

NOTES: UNLESS OTHERWISE SPECIFIED

- 1. ALL DIMENSIONS ARE IN MILLIMETERS.
- 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 3. PACKAGE OUTLINE REFERENCE: JEDEC TO-236, ISSUE H, VARIATION AA.
- 4. MOLDED PLASTIC BODY DIMENSIONS DO NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS.
- 5. DWG NO REF: HQ2SD07-025 REV A.

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